TEXAS INSTRUMENTS

ISO7142CC-Q1

SLLSER5 –DECEMBER 2015

ISO7142CC-Q1 4242-V_{PK} Small-Footprint and Low-Power Quad Channel Digital Isolator

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: –40°C to +125°C Ambient Operating Temperature Range
  - Device HBM Classification Level 3A
  - Device CDM Classification Level C6
- Maximum Signaling Rate: 50 Mbps (with 5-V Supplies)
- Robust Design With Integrated Noise Filter
- Low-Power Consumption, Typical I_{CC} per Channel (With 3.3-V Supplies):
  - 1.3 mA at 1 Mbps, 2.5 mA at 25 Mbps
- 50 kV/µs Transient Immunity, Typical
- Long Life with SiO_2 Isolation Barrier
- Operates From 2.7-V, 3.3-V and 5-V Supply
- 2.7-V to 5.5-V Level Translation
- Small QSOP-16 Package
- Safety and Regulatory Approvals
  - 2500-V_{RMS} Isolation for 1 Minute per UL 1577
  - 4242-V_{PK} Isolation per DIN V VDE V 0884-10 (VDE V 0884-10):2006-12
  - CSA Component Acceptance Notice 5A, IEC 60950-1 and IEC 61010-1 End Equipment Standards
  - Planned CQC Certification per GB4943.1-2011

2 Applications

- General Purpose Isolation
- Industrial Automation
- Motor Control
- Solar Inverters

3 Description

The ISO7142CC-Q1 device provides galvanic isolation up to 2500 V_{RMS} for 1 minute per UL 1577 and 4242-V_{PK} per VDE V 0884-10. The ISO7142CC-Q1 is a quad-channel isolator with two forward and two reverse-direction channels. This device is capable of maximum data rate of 50 Mbps with 5-V supplies and 40 Mbps with 3.3-V or 2.7-V supplies. The ISO7142CC-Q1 device has integrated filters on the inputs to support noise-prone applications.
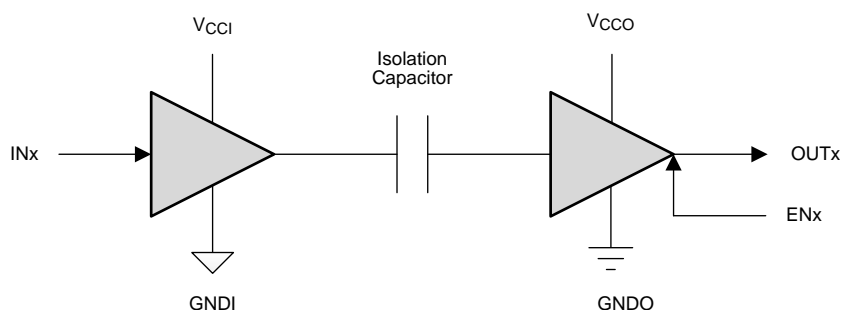
Each isolation channel has a logic input and output buffer separated by a silicon dioxide (SiO_2) insulation barrier. Used in conjunction with isolated power supplies, this device prevents noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry. This device has TTL input thresholds and can operate from 2.7-V, 3.3-V, and 5-V supplies.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
ISO7142CC-Q1	SSOP (16)	4.90 mm × 3.90 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

V_{CCI} and GNDI are supply and ground connections respectively for the input channels.

V_{CCO} and GNDO are supply and ground connections respectively for the output channels.
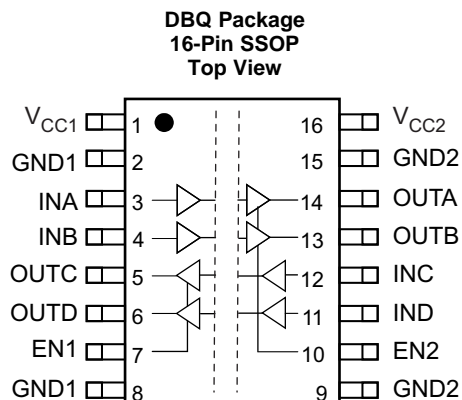
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
December 2015	*	Initial release.

5 Pin Configuration and Functions

DBQ Package
16-Pin SSOP
Top View

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V_CC1   ⊏ 1  ●        16 ⊐  V_CC2
GND1    ⊏ 2           15 ⊐  GND2
INA     ⊏ 3  ▷     ◁  14 ⊐  OUTA
INB     ⊏ 4  ▷     ◁  13 ⊐  OUTB
OUTC    ⊏ 5  ◁     ▷  12 ⊐  INC
OUTD    ⊏ 6  ◁     ▷  11 ⊐  IND
EN1     ⊏ 7           10 ⊐  EN2
GND1    ⊏ 8            9 ⊐  GND2
```

Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
EN1	7	I	Output enable 1. Output pins on side 1 are enabled when EN1 is high or open and in high-impedance state when EN1 is low.
EN2	10	I	Output enable 2. Output pins on side 2 are enabled when EN2 is high or open and in high-impedance state when EN2 is low.
GND1	2	—	Ground connection for V_{CC1}
	8		
GND2	9	—	Ground connection for V_{CC2}
	15		
INA	3	I	Input, channel A
INB	4	I	Input, channel B
INC	12	I	Input, channel C
IND	11	I	Input, channel D
OUTA	14	O	Output, channel A
OUTB	13	O	Output, channel B
OUTC	5	O	Output, channel C
OUTD	6	O	Output, channel D
V_{CC1}	1	—	Power supply, V_{CC1}
V_{CC2}	16	—	Power supply, V_{CC2}

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

			MIN	MAX	UNIT
	Supply voltage[2]	V_{CC1}, V_{CC2}	−0.5	6	V
	Voltage	INx, OUTx, ENx	−0.5	V_{CC} + 0.5[3]	V
I_O	Output current		−15	15	mA
T_J	Maximum junction temperature			150	°C
T_{stg}	Storage temperature		−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values.
(3) Maximum voltage must not exceed 6 V.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002[1]	±4000	V
		Charged-device model (CDM), per AEC Q100-011	±1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{CC1}, V_{CC2}	Supply voltage		2.7		5.5	V
I_{OH}	High-level output current	$V_{CC} \geq 3$ V	−4			mA
		$V_{CC} < 3$ V	−2			
I_{OL}	Low-level output current				4	mA
V_{IH}	High-level input voltage		2		5.5	V
V_{IL}	Low-level input voltage		0		0.8	V
t_{ui}	Input pulse duration	$V_{CC} \geq 4.5$ V	20			ns
		$V_{CC} < 4.5$ V	25			
$1 / t_{ui}$	Signaling rate	$V_{CC} \geq 4.5$ V	0		50	Mbps
		$V_{CC} < 4.5$ V	0		40	
T_J	Junction temperature				136	°C
T_A	Ambient temperature		−55	25	125	°C

6.4 Thermal Information

		ISO7142CC-Q1	
	THERMAL METRIC[1]	DBQ (SSOP)	UNIT
		16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	104.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	57.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	46.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	18.3	°C/W
ψ_{JB}	Junction-to-board characterization parameter	46.4	°C/W
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics—5-V Supply

V_{CC1} and V_{CC2} at 5 V ± 10% (over recommended operating conditions unless otherwise noted.)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = −4 mA; see Figure 8	V_{CCO} [(1)] − 0.5				V
		I_{OH} = −20 µA; see Figure 8	V_{CCO} − 0.1				
V_{OL}	Low-level output voltage	I_{OL} = 4 mA; see Figure 8				0.4	V
		I_{OL} = 20 µA; see Figure 8				0.1	
$V_{I(HYS)}$	Input threshold voltage hysteresis				480		mV
I_{IH}	High-level input current	V_{IH} = V_{CCI} [(1)] at INx or ENx				10	µA
I_{IL}	Low-level input current	V_{IL} = 0 V at INx or ENx		−10			
CMTI	Common-mode transient immunity	V_I = V_{CCI} or 0 V; see Figure 11		25	70		kV/µs

(1) V_{CCI}= Supply voltage for the input channel; V_{CCO} = Supply voltage for the output channel

6.6 Supply Current Characteristics—5-V Supply

V_{CC1} and V_{CC2} at 5 V ± 10% (over recommended operating conditions unless otherwise noted.)

PARAMETER	SUPPLY CURRENT			MIN	TYP	MAX	UNIT
Supply current for V_{CC1} and V_{CC2}	Disable	EN1 = EN2 = 0 V	I_{CC1}, I_{CC2}		0.8	1.6	mA
	DC to 1 Mbps	DC signal: V_I = V_{CCI} or 0 V, AC signal: All channels switching with square wave clock input; C_L = 15 pF	I_{CC1} , I_{CC2}		3.3	5	
	10 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		4.9	7	
	25 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		7.3	10	
	50 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		11.1	14.5	

6.7 Electrical Characteristics—3.3-V Supply

V_{CC1} and V_{CC2} at 3.3 V ± 10% (over recommended operating conditions unless otherwise noted.)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = −4 mA; see Figure 8	V_{CCO} [(1)] − 0.5				V
		I_{OH} = −20 µA; see Figure 8	V_{CCO} − 0.1				
V_{OL}	Low-level output voltage	I_{OL} = 4 mA; see Figure 8				0.4	V
		I_{OL} = 20 µA; see Figure 8				0.1	
$V_{I(HYS)}$	Input threshold voltage hysteresis				460		mV
I_{IH}	High-level input current	V_{IH} = V_{CCI} [(1)] at INx or ENx				10	µA
I_{IL}	Low-level input current	V_{IL} = 0 V at INx or ENx		−10			
CMTI	Common-mode transient immunity	V_I = V_{CCI} or 0 V; see Figure 11		25	50		kV/µs

(1) V_{CCI}= Supply voltage for the input channel; V_{CCO} = Supply voltage for the output channel

6.8 Supply Current Characteristics—3.3-V Supply

V_{CC1} and V_{CC2} at 3.3 V ± 10% (over recommended operating conditions unless otherwise noted.)

PARAMETER	TEST CONDITIONS		SUPPLY CURRENT	MIN	TYP	MAX	UNIT
Supply current for V_{CC1} and V_{CC2}	Disable	EN1 = EN2 = 0 V	I_{CC1}, I_{CC2}		0.5	1	mA
	DC to 1 Mbps	DC signal: $V_I = V_{CCI}$ or 0 V AC signal: All channels switching with square-wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		2.5	4	
	10 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		3.5	5	
	25 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		5	7	
	40 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		6.5	10	

6.9 Electrical Characteristics—2.7-V Supply

V_{CC1} and V_{CC2} at 2.7 V (over recommended operating conditions unless otherwise noted.)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = –2 mA; see Figure 8	V_{CCO} [1] – 0.3			V
		I_{OH} = –20 µA; see Figure 8	V_{CCO} – 0.1			
V_{OL}	Low-level output voltage	I_{OL} = 4 mA; see Figure 8			0.4	V
		I_{OL} = 20 µA; see Figure 8			0.1	
$V_{I(HYS)}$	Input threshold voltage hysteresis			360		mV
I_{IH}	High-level input current	$V_{IH} = V_{CCI}$[1] at INx or ENx			10	µA
I_{IL}	Low-level input current	V_{IL} = 0 V at INx or ENx	–10			
CMTI	Common-mode transient immunity	$V_I = V_{CCI}$ or 0 V; see Figure 11	25	45		kV/µs

(1) V_{CCI} = Supply voltage for the input channel; V_{CCO} = Supply voltage for the output channel

6.10 Supply Current Characteristics—2.7-V Supply

V_{CC1} and V_{CC2} at 2.7 V (over recommended operating conditions unless otherwise noted.)

PARAMETER	TEST CONDITIONS		SUPPLY CURRENT	MIN	TYP	MAX	UNIT
Supply current for V_{CC1} and V_{CC2}	Disable	EN1 = EN2 = 0 V	I_{CC1}, I_{CC2}		0.4	0.8	mA
	DC to 1 Mbps	DC signal: $V_I = V_{CCI}$ or 0 V AC signal: All channels switching with square-wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		2.2	3.5	
	10 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		3	4.2	
	25 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		4.2	5.5	
	40 Mbps	All channels switching with square wave clock input; C_L = 15 pF	I_{CC1}, I_{CC2}		5.4	7.5	

6.11 Power Dissipation Characteristics

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_D	Device power dissipation	$V_{CC1} = V_{CC2}$ = 5.5 V, T_J = 150°C, C_L = 15 pF Input a 25-MHz, 50% duty cycle square wave			170	mW

6.12 Switching Characteristics—5-V Supply

V_{CC1} and V_{CC2} at 5 V ± 10% (over recommended operating conditions unless otherwise noted.)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL}	Propagation delay time	See Figure 8	15	21	38	ns
PWD[1]	Pulse width distortion $|t_{PHL} - t_{PLH}|$	See Figure 8			3.5	ns
$t_{sk(o)}$ [2]	Channel-to-channel output skew time	Same-direction channels			1.5	ns
		Opposite-direction channels			6.5	
$t_{sk(pp)}$ [3]	Part-to-part skew time				14	ns
t_r	Output signal rise time	See Figure 8		2.5		ns
t_f	Output signal fall time	See Figure 8		2.1		ns
t_{PHZ}, t_{PLZ}	Disable propagation delay, high/low-to-high impedance output	See Figure 9		7	12	ns
t_{PZH}	Enable propagation delay, high impedance-to-high output	See Figure 9		6	12	ns
t_{PZL}	Enable propagation delay, high impedance-to-low output	See Figure 9		12	23	us
t_{fs}	Fail-safe output delay time from input data or power loss	See Figure 10		8		µs
t_{GR}	Input glitch rejection time			9.5		ns

(1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
(3) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals, and loads.

6.13 Switching Characteristics—3.3-V Supply

V_{CC1} and V_{CC2} at 3.3 V ± 10% (over recommended operating conditions unless otherwise noted.)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL}	Propagation delay time	See Figure 8	16	25	46	ns
PWD[1]	Pulse width distortion $|t_{PHL} - t_{PLH}|$	See Figure 8			3	ns
$t_{sk(o)}$ [2]	Channel-to-channel output skew time	Same-direction Channels			2	ns
		Opposite-direction Channels			6.5	
$t_{sk(pp)}$ [3]	Part-to-part skew time				21	ns
t_r	Output signal rise time	See Figure 8		3		ns
t_f	Output signal fall time	See Figure 8		2.5		ns
t_{PHZ}, t_{PLZ}	Disable propagation delay, from high/low to high-impedance output	See Figure 9		9	14	ns
t_{PZH}	Enable propagation delay, from high-impedance to high output	See Figure 9		9	17	ns
t_{PZL}	Enable propagation delay, from high-impedance to low output	See Figure 9		12	24	us
t_{fs}	Fail-safe output delay time from input data or power loss	See Figure 10		7		µs
t_{GR}	Input glitch rejection time			11		ns

(1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
(3) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

6.14 Switching Characteristics—2.7-V Supply

V_{CC1} and V_{CC2} at 2.7 V (over recommended operating conditions unless otherwise noted.)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}, t_{PHL}	Propagation delay time	See Figure 8	18	28	50	ns
PWD[1]	Pulse width distortion $\|t_{PHL} - t_{PLH}\|$	See Figure 8			3	ns
$t_{sk(o)}$ [2]	Channel-to-channel output skew time	Same-direction Channels			3	ns
		Opposite-direction Channels			8.5	ns
$t_{sk(pp)}$ [3]	Part-to-part skew time				24	ns
t_r	Output signal rise time	See Figure 8		3.5		ns
t_f	Output signal fall time	See Figure 8		2.8		ns
t_{PHZ}, t_{PLZ}	Disable propagation delay, from high/low to high-impedance output	See Figure 9		10	15	ns
t_{PZH}	Enable propagation delay, from high-impedance to high output	See Figure 9		10	19	ns
t_{PZL}	Enable propagation delay, from high-impedance to low output	See Figure 9		12	23	us
t_{fs}	Fail-safe output delay time from input data or power loss	See Figure 10		7		μs
t_{GR}	Input glitch rejection time			12		ns

(1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
(3) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals, and loads.
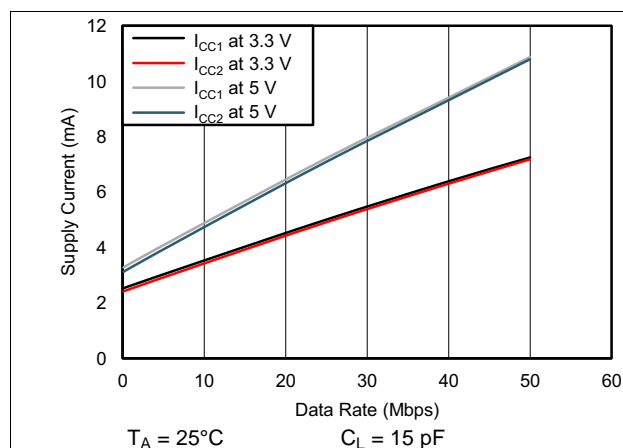
6.15 Typical Characteristics

$T_A = 25°C$ $C_L = 15$ pF

Figure 1. ISO7142CC-Q1 Supply Current for All Channels vs Data Rate

$T_A = 25°C$

Figure 2. High-Level Output Voltage vs High-Level Output Current

Product Folder Links: *ISO7142CC-Q1*

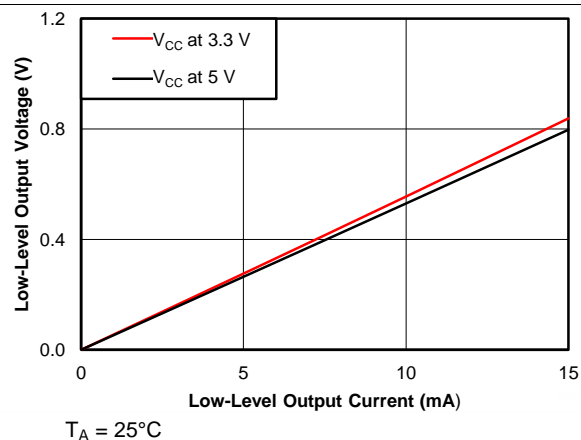## Typical Characteristics (continued)

Figure 3. Low-Level Output Voltage
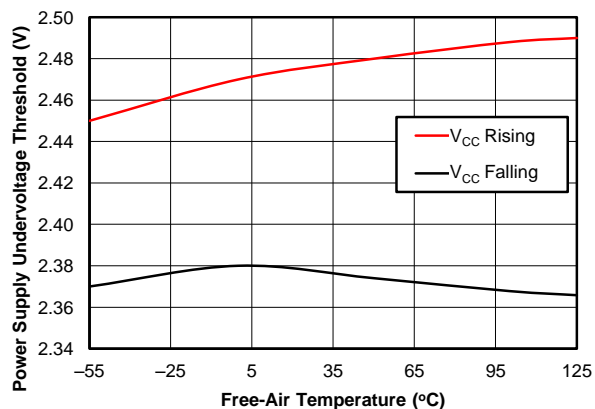vs Low-Level Output Current

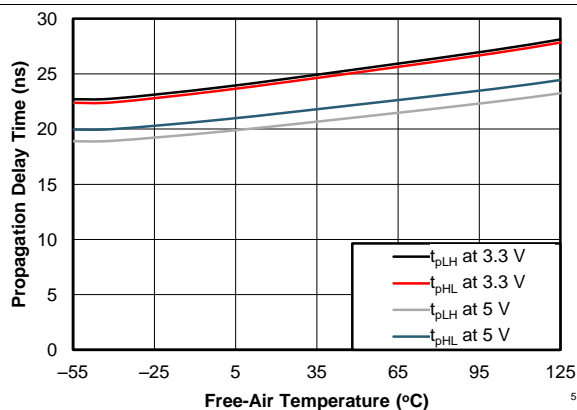Figure 4. V$_{CC}$ Undervoltage Threshold
vs Free-Air Temperature

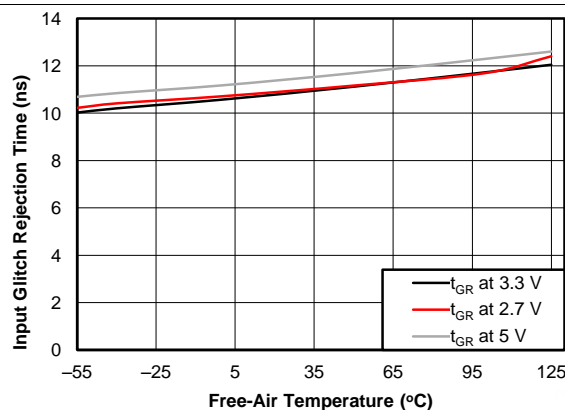Figure 5. Propagation Delay Time
vs Free-Air Temperature

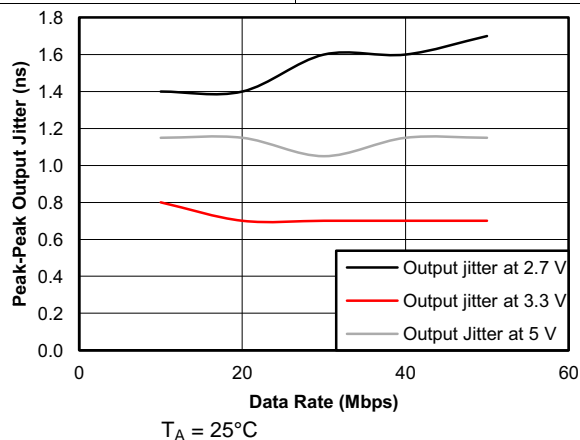Figure 6. Input Glitch Rejection Time
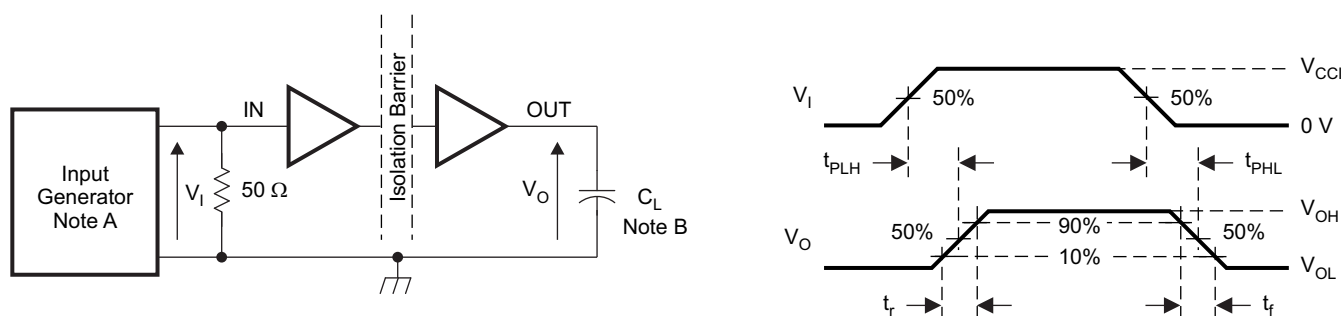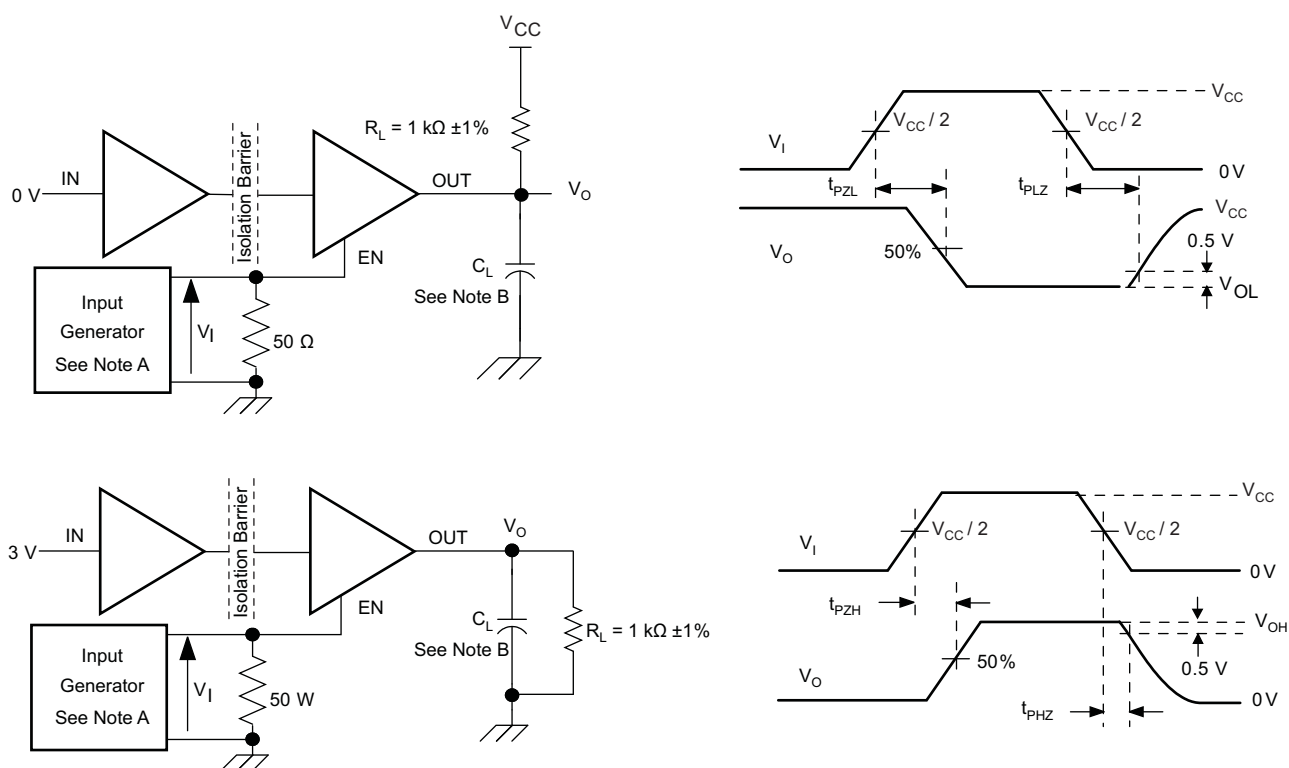vs Free-Air Temperature

Figure 7. Peak-Peak Output Jitter vs Data Rate

7 Parameter Measurement Information

A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 50 kHz, 50% duty cycle, t_r ≤ 3 ns, t_f ≤ 3 ns, Z_O = 50 Ω. At the input, a 50-Ω resistor is required to terminate the input-generator signal. It is not needed in an actual application.

B. C_L = 15 pF and includes instrumentation and fixture capacitance within ±20%.

Figure 8. Switching-Characteristics Test Circuit and Voltage Waveforms

A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 50 kHz, 50% duty cycle, t_r ≤ 3 ns, t_f ≤ 3 ns, Z_O = 50 Ω.

B. C_L = 15 pF and includes instrumentation and fixture capacitance within ±20%.

Figure 9. Enable/Disable Propagation Delay-Time Test Circuit and Waveform

Product Folder Links: *ISO7142CC-Q1*

Parameter Measurement Information (continued)

A. C_L = 15 pF and includes instrumentation and fixture capacitance within ±20%.

Figure 10. Failsafe Delay-Time Test Circuit and Voltage Waveforms

A. C_L = 15pF and includes instrumentation and fixture capacitance within ±20%.

Figure 11. Common-Mode Transient Immunity Test Circuit

Product Folder Links: *ISO7142CC-Q1*

8 Detailed Description

8.1 Overview

The isolator in Figure 12 is based on a capacitive isolation barrier technique. The I/O channel of the device consists of two internal data channels, a high-frequency channel (HF) with a bandwidth from 100 kbps up to 50 Mbps, and a low-frequency channel (LF) covering the range from 100 kbps down to DC. In principle, a single-ended input signal entering the HF-channel is split into a differential signal through the inverter gate at the input. The following capacitor-resistor networks differentiate the signal into transients, which then are converted into differential pulses by two comparators. The comparator outputs drive a NOR-gate flip-flop whose output feeds an output multiplexer. A decision logic (DCL) at the driving output of the flip-flop measures the durations between signal transients. If the duration between two consecutive transients exceeds a certain time limit, (as in the case of a low-frequency signal), the DCL forces the output-multiplexer to switch from the high- to the low-frequency channel.

Because low-frequency input signals require the internal capacitors to assume prohibitively large values, these signals are pulse-width modulated (PWM) with the carrier frequency of an internal oscillator, thus creating a sufficiently high frequency signal, capable of passing the capacitive barrier. As the input is modulated, a low-pass filter (LPF) is needed to remove the high-frequency carrier from the actual data before passing it on to the output multiplexer.
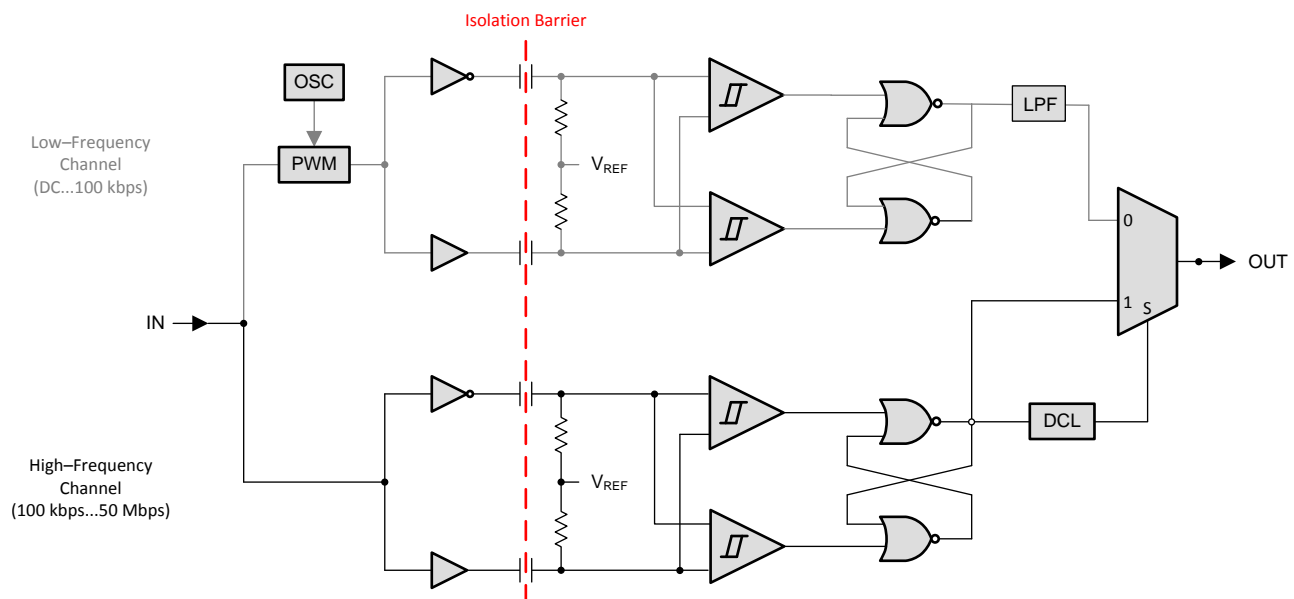
8.2 Functional Block Diagram

Figure 12. Conceptual Block Diagram of a Digital Capacitive Isolator

Product Folder Links: *ISO7142CC-Q1*

8.3 Feature Description

8.3.1 Insulation and Safety-Related Specifications

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DTI	Distance through the insulation	Minimum internal gap (internal clearance)	0.014			mm
C_I [(1)]	Input capacitance	$V_I = V_{CC}/2 + 0.4 \sin(2\pi ft)$, f = 1 MHz, V_{CC} = 5 V		2		pF
DIN V VDE V 0884-10 (VDE V 0884-10):2006-12						
V_{IOTM}	Maximum transient isolation voltage				4242	V_{PK}
V_{IORM}	Maximum working isolation voltage				566	V_{PK}
V_{PR}	Input-to-output test voltage	After Input/Output safety test subgroup 2/3, $V_{PR} = V_{IORM}$ x 1.2, t = 10 s, Partial discharge < 5 pC			679	V_{PK}
		Method a, After environmental tests subgroup 1, $V_{PR} = V_{IORM}$ x 1.6, t = 10 s, Partial discharge < 5 pC			906	
		Method b1, 100% production test, $V_{PR} = V_{IORM}$ x 1.875, t = 1 s, Partial discharge < 5 pC			1061	
L(I01)	Minimum air gap (clearance)	Shortest terminal to terminal distance through air	3.7			mm
L(I02)	Minimum external tracking (creepage)	Shortest terminal to terminal distance across the package surface	3.7			mm
	Pollution degree			2		
CTI	Tracking resistance (comparative tracking index)	DIN EN 60112 (VDE 0303-11); IEC 60112	≥400			V
R_{IO} [(2)]	Isolation resistance, input to output	V_{IO} = 500 V, $T_A = 25^oC$		$>10^{12}$		Ω
		V_{IO} = 500 V, $100^oC \le T_A \le 125^oC$		$>10^{11}$		
		V_{IO} = 500 V, $T_S = 150^oC$		$>10^9$		
C_{IO} [(2)]	Barrier capacitance, input to output	$V_I = 0.4 \sin(2\pi ft)$, f = 1 MHz		2.4		pF
UL 1577						
V_{ISO}	Withstanding Isolation voltage	$V_{TEST} = V_{ISO}$= 2500 V_{RMS}, 60 sec (qualification); V_{TEST} = 1.2 * V_{ISO}= 3000 V_{RMS}, 1 sec (100% production)			2500	V_{RMS}

(1) Measured from input data pin to ground.
(2) All pins on each side of the barrier tied together creating a two-terminal device.

NOTE

Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board do not reduce this distance.

Creepage and clearance on a printed circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.

Table 1. IEC 60664-1 Ratings Table

PARAMETER	TEST CONDITIONS	SPECIFICATION
Material Group		II
Installation classification / Overvoltage Category for Basic Insulation	Rated mains voltage ≤ 150 V_{RMS}	I–IV
	Rated mains voltage ≤ 300 V_{RMS}	I–III

8.3.2 Regulatory Information

VDE	UL	CSA	CQC
Certified according to DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 and DIN EN 61010-1 (VDE 0411-1):2011-07	Certified under UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A, IEC 60950-1 and IEC 61010-1	Plan to certify according to GB 4943.1-2011
Basic Insulation; Maximum transient Isolation IsolatiIsolationvoltage, 4242 V_{PK} Maximum working isolation voltage, 566 V_{PK}	Single protection, 2500 V_{RMS} [(1)]	3000 V_{RMS} Isolation rating; 185 V_{RMS} Reinforced Insulation and 370 V_{RMS} Basic Insulation per CSA 60950-1-07+A1+A2 and IEC 60950-1 2nd Ed.+A1+A2; 150 V_{RMS} Reinforced Insulation and 300 V_{RMS} Basic Insulation per CSA 61010-1-12 and IEC 61010-1 3rd Ed.	Basic Insulation, Altitude ≤ 5000m, Tropical climate, 250 V_{RMS} maximum working voltage.
File number: 40016131	File number: E181974	Master contract number: 220991	Certification Planned

(1)   Production tested ≥ 3000 V_{RMS} for 1 second in accordance with UL 1577.

8.3.3 Safety Limiting Values

Safety limiting intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the IO can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier, potentially leading to secondary system failures.

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_S	Safety input, output, or supply current	DBQ-16	θ_{JA} = 104.5°C/W, V_I = 5.5 V, T_J = 150°C, T_A = 25°C			217	mA
			θ_{JA} = 104.5°C/W, V_I = 3.6 V, T_J = 150°C, T_A = 25°C			332	
			θ_{JA} = 104.5°C/W, V_I = 2.7 V, T_J = 150°C, T_A = 25°C			443	
T_S	Maximum safety temperature					150	°C

The safety-limiting constraint is the absolute-maximum junction temperature specified in the *Absolute Maximum Ratings* table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the *Thermal Information* table is that of a device installed on a high-K test board for leaded surface-mount packages. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.
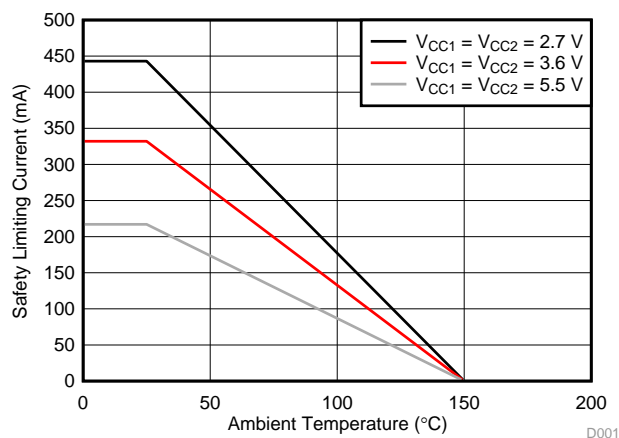

Figure 13. Thermal Derating Curve for Safety Limiting Current per VDE

8.4 Device Functional Modes

Table 2 lists the functional modes for the ISO7142CC-Q1.

Table 2. Function Table[1]

V_{CCI}	V_{CCO}	INPUT (INx)	OUTPUT ENABLE (ENx)	OUTPUT (OUTx)
PU	PU	H	H or open	H
		L	H or open	L
		X	L	Z
		Open	H or open	H
PD	PU	X	H or open	H
PD	PU	X	L	Z
X	PD	X	X	Undetermined

(1) V_{CCI} = Input-side Supply Voltage; V_{CCO} = Output-side Supply Voltage; PU = Powered Up ($V_{CC} \geq 2.7$ V); PD = Powered Down ($V_{CC} \leq 2.1$ V); X = Irrelevant; H = High Level; L = Low Level; Z = High Impedance
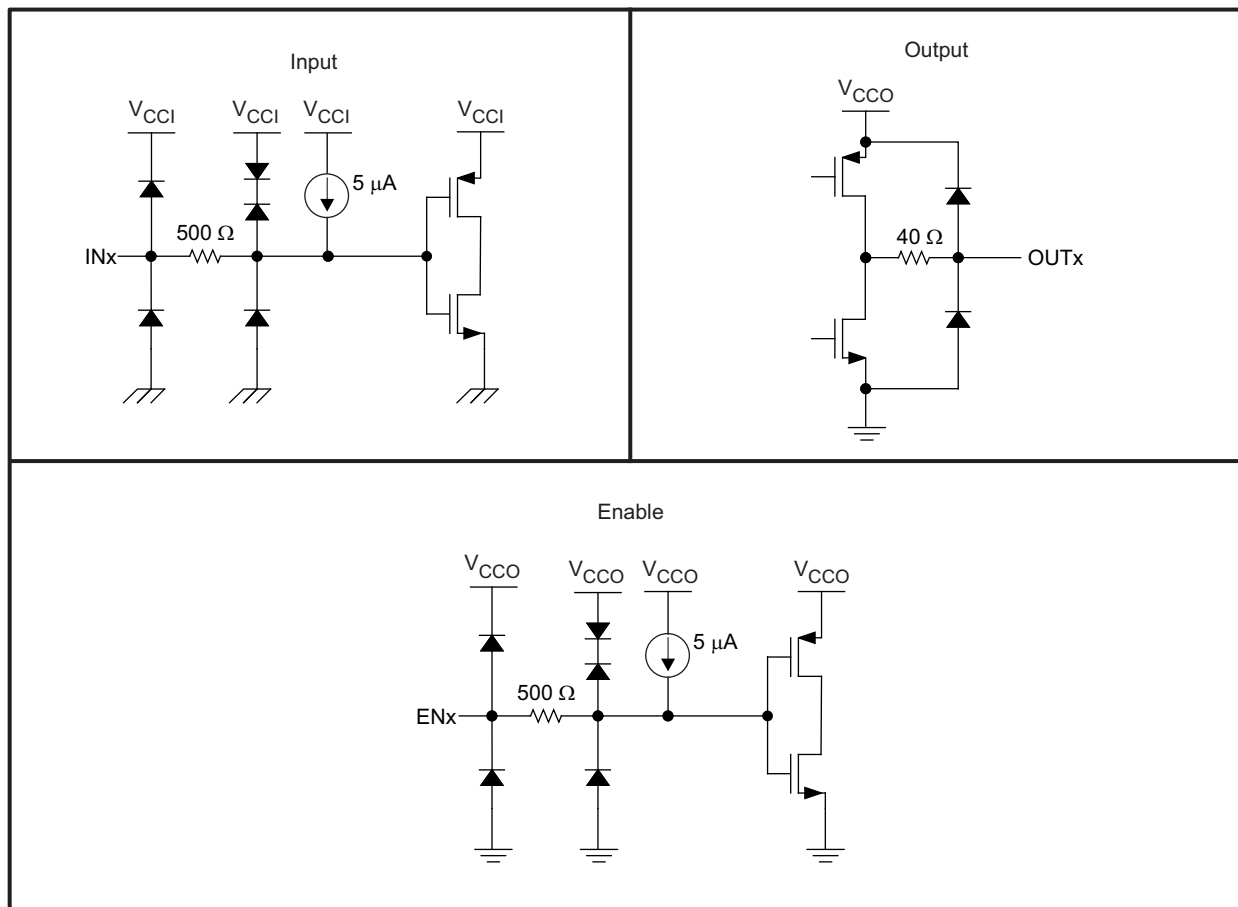
8.4.1 Device I/O Schematics

Figure 14. Device I/O Schematics

Product Folder Links: *ISO7142CC-Q1*

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The ISO7142CC-Q1 device uses single-ended TTL-logic switching technology. The supply voltage range is from 2.7 V to 5.5 V for both supplies, V_{CC1} and V_{CC2}. When designing with digital isolators, keep in mind that because of the single-ended design structure the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is, µC or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

9.2 Typical Application

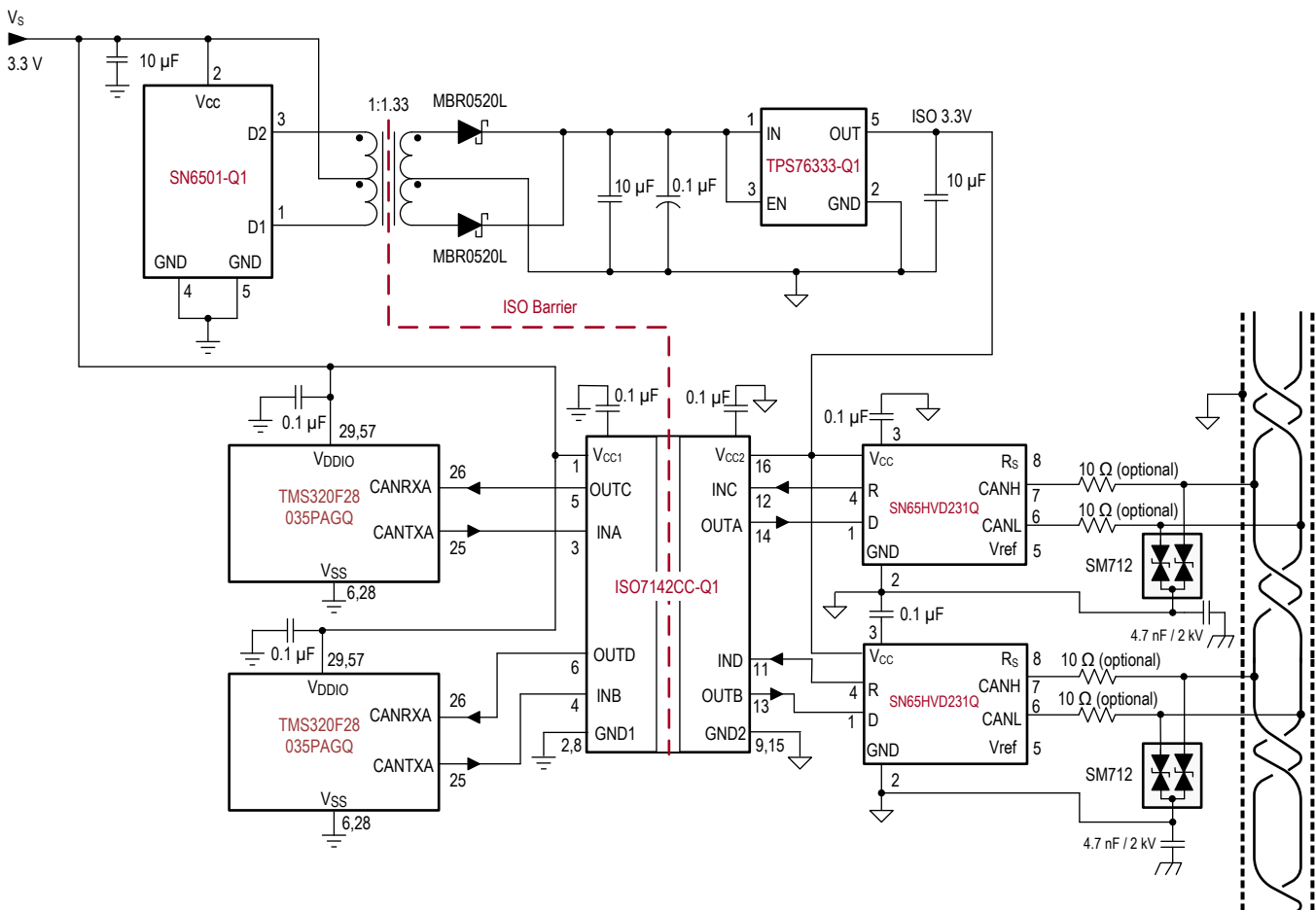Figure 15 shows the typical isolated CAN interface implementation.

Figure 15. Typical Isolated CAN Application Circuit for ISO7142CC-Q1

9.2.1 Design Requirements

Unlike optocouplers, which require external components to improve performance, provide bias, or limit current, the ISO7142CC-Q1 device only requires two external bypass capacitors to operate.

Typical Application (continued)

9.2.2 Detailed Design Procedure

Figure 16 shows the hookup of a typical ISO7142CC-Q1 circuit. The only external components are two bypass capacitors.
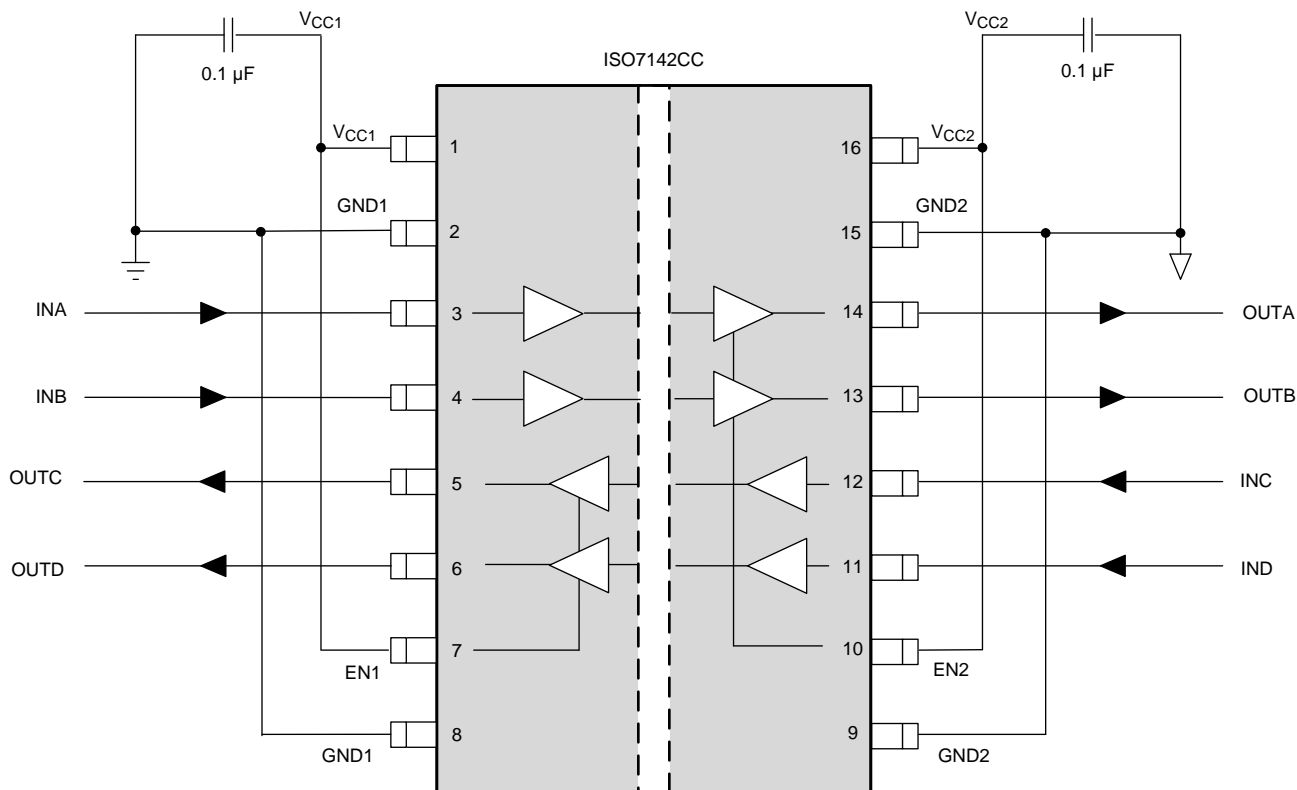

Figure 16. Typical ISO7142CC-Q1 Circuit Hook-up
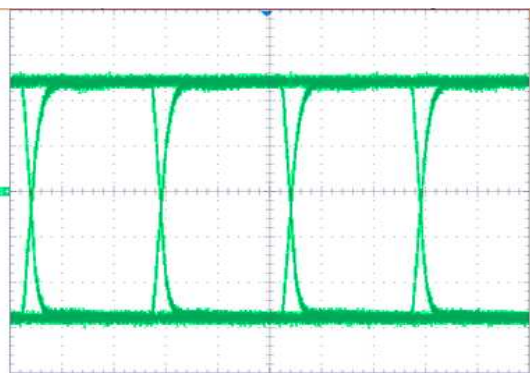
9.2.3 Application Curves

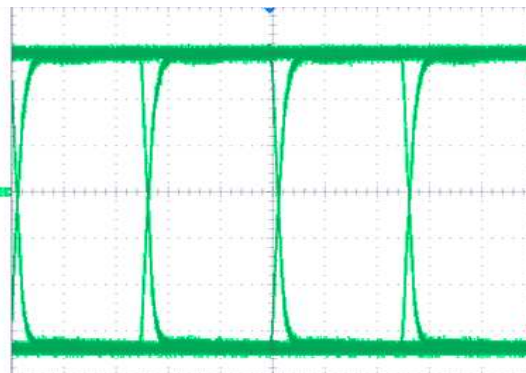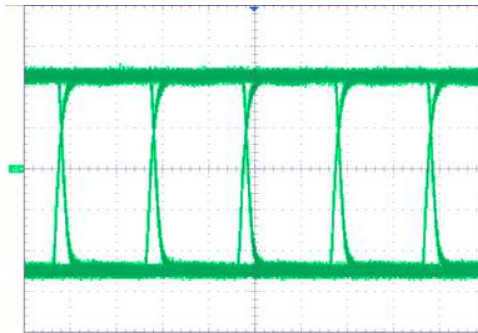**Figure 17. Typical Eye Diagram at 40 Mbps, PRBS 2^{16} - 1, 2.7-V Operation**

Figure 18. Typical Eye Diagram at 40 Mbps, PRBS 2^{16} - 1, 3.3-V Operation

Product Folder Links: *ISO7142CC-Q1*

Typical Application (continued)

**Figure 19. Typical Eye Diagram at 50 Mbps,
PRBS 2^{16} - 1, 5-V Operation**

10 Power Supply Recommendations

To help ensure reliable operation supply voltages, a 0.1-µF bypass capacitor is recommended at the input and output supply pins (V_{CC1} and V_{CC2}). The capacitors should be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments' SN6501-Q1. For such applications, detailed power supply design and transformer selection recommendations are available in SN6501-Q1 datasheet (SLLSEF3).

11 Layout

11.1 Layout Guidelines

A minimum of four layers is required to accomplish a low EMI PCB design (see Figure 20). Layer stacking should be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of their inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100 pF/in^2.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links usually have margin to tolerate discontinuities such as vias.

If an additional supply voltage plane or signal layer is needed, add a second power and ground plane system to the stack to keep it symmetrical. This makes the stack mechanically stable and prevents it from warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, see the application note, *Digital Isolator Design Guide*, SLLA284.

Product Folder Links: *ISO7142CC-Q1*

Layout Guidelines (continued)

11.1.1 PCB Material

For digital circuit boards operating below 150 Mbps, (or rise and fall times higher than 1 ns), and trace lengths of up to 10 inches, use standard FR-4 UL 94 V-0 printed circuit board. This PCB is preferred over cheaper alternatives because of lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and self-extinguishing flammability-characteristics.
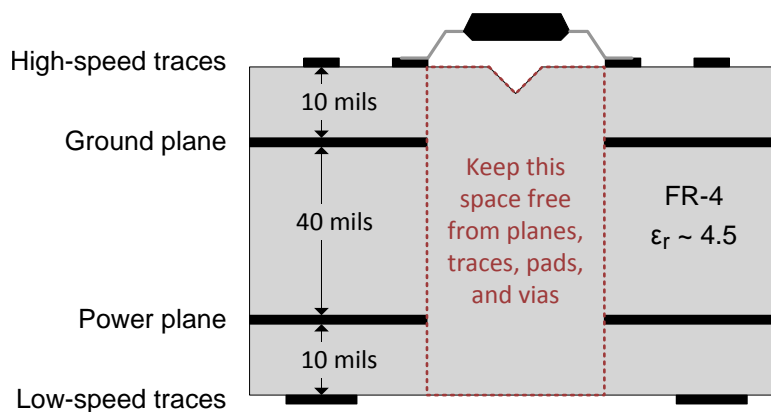
11.2 Layout Example

Figure 20. Recommended Layer Stack

Product Folder Links: *ISO7142CC-Q1*

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:
- *Digital Isolator Design Guide*, SLLA284
- *Isolation Glossary*, SLLA353
- *ISO71xx EVM User's Guide*, SLLU179
- *SN6501-Q1 Transformer Driver for Isolated Power Supplies*, SLLSEF3
- SN65HVD231Q-Q1 *3.3-V CAN Transceivers*, SGLS398
- TMS320F28035 *Piccolo™ Microcontrollers*, SPRS584
- TPS76333-Q1 *Low-Power 150-mA Low-Dropout Linear Regulators*, SGLS247

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

Piccolo, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ISO7142CCQDBQQ1	Active	Production	SSOP (DBQ) | 16	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	7142Q
ISO7142CCQDBQQ1.A	Active	Production	SSOP (DBQ) | 16	75 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	7142Q
ISO7142CCQDBQRQ1	Active	Production	SSOP (DBQ) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	7142Q
ISO7142CCQDBQRQ1.A	Active	Production	SSOP (DBQ) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	7142Q

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF ISO7142CC-Q1 :

● Catalog : ISO7142CC

NOTE: Qualified Version Definitions:
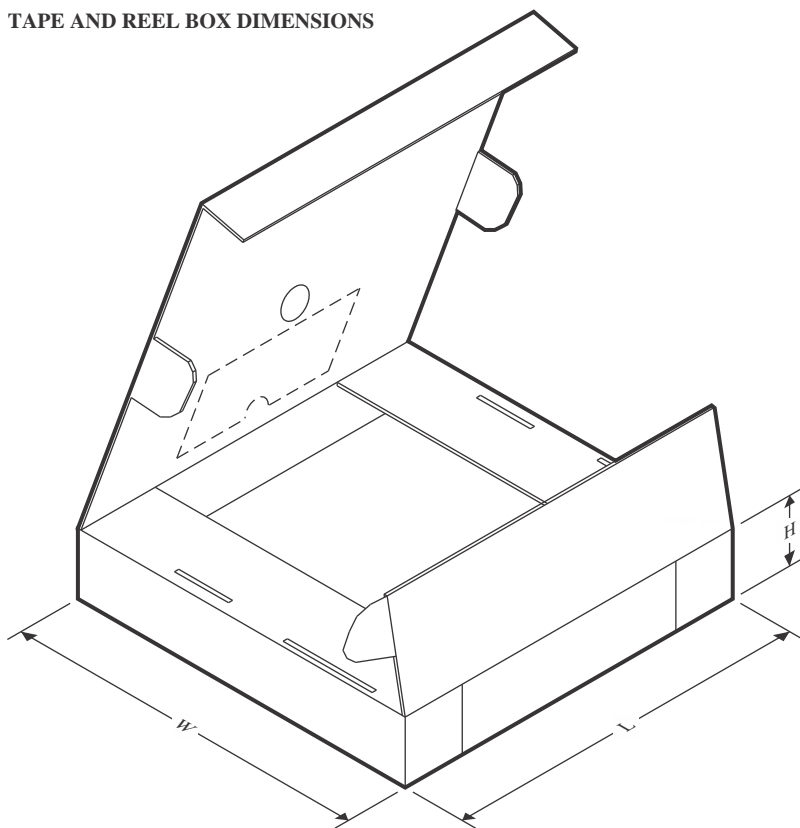
    ● Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ISO7142CCQDBQRQ1	SSOP	DBQ	16	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

![Texas Instruments logo]

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO7142CCQDBQRQ1	SSOP	DBQ	16	2500	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

TUBE

T - Tube height

L - Tube length

W - Tube width

B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
ISO7142CCQDBQQ1	DBQ	SSOP	16	75	505.46	6.76	3810	4
ISO7142CCQDBQQ1.A	DBQ	SSOP	16	75	505.46	6.76	3810	4

.228-.244 TYP
[5.80-6.19]

PIN 1 ID AREA

14X .0250
[0.635]

2X
.175
[4.45]

.189-.197
[4.81-5.00]
NOTE 3

16X .008-.012
[0.21-0.30]

⊕ .007 [0.17]Ⓜ C AⓈ BⓈ

.150-.157
[3.81-3.98]
NOTE 4

C

SEATING PLANE

⌒ .004 [0.1] C

.069 MAX
[1.75]

SEE DETAIL A

.005-.010 TYP
[0.13-0.25]

.010
[0.25]
GAGE PLANE

0° - 8°

.016-.035
[0.41-0.88]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214846/A   03/2014

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 inch, per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MO-137, variation AB.

16X (.063)
[1.6]

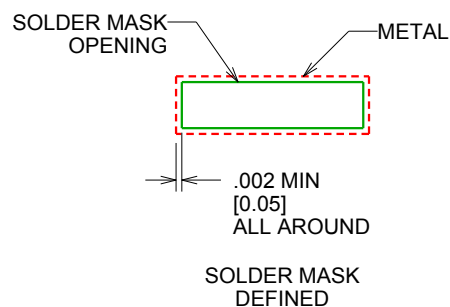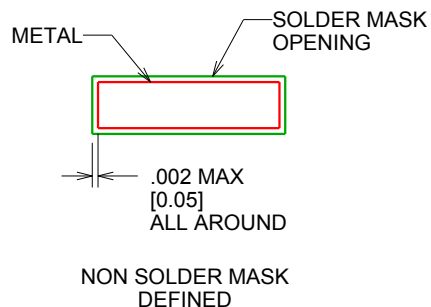SYMM

SEE
DETAILS

1

16

16X (.016)
[0.41]

14X (.0250)
[0.635]

8

9

(.213)
[5.4]

LAND PATTERN EXAMPLE
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL

.002 MAX
[0.05]
ALL AROUND

.002 MIN
[0.05]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214846/A   03/2014

NOTES: (continued)
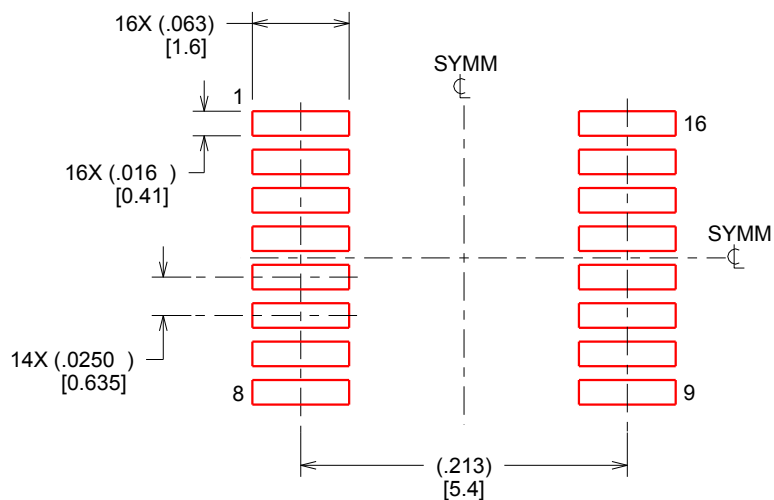
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

16X (.063)
[1.6]

SYMM

1

16X (.016)
[0.41]

16

SYMM

14X (.0250)
[0.635]

8

9

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.127 MM] THICK STENCIL
SCALE:8X

4214846/A   03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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